Chip Monolithic Ceramic Capacitors

muRata

for Flow/Reflow Soldering GRM15/18/21/31 Series

Features

- 1. Terminations are made of metal highly resistant to migration.
- 2. The GRM series is a complete line of chip ceramic capacitors in 6.3V, 10V, 16V, 25V, 50V, 100V, 200V and 500V ratings. These capacitors have temperature characteristics ranging from C0G to Y5V.
- A wide selection of sizes is available, from the miniature LxWxT: 1.0x0.5x0.5mm to LxWxT: 3.2x1.6x1.15mm.
 GRM18, 21 and GRM31 types are suited to flow and reflow soldering.

GRM15 type is applied to only reflow soldering.

- 4. Stringent dimensional tolerances allow highly reliable, high speed automatic chip placement on PCBs.
- 5. The GRM series is available in paper or plastic embossed tape and reel packaging for automatic placement. Bulk case packaging is also available for GRM15, GRM18 and GRM21.

Applications

General electronic equipment

Temperature Compensating Type GRM15 Series (1.0x0.5 mm) 50V/25V

Part Number				GR	M15						
L x W [EIA]				1.00x0.	50 [0402]						
тс	C0G (5C)	P2H (6P)	R2H (6R)	S2H (6S)	(*	SL I X)	T2H (6T)	U2J (7U)			
Rated Volt.	50 (1H)	50 (1H)	50 (1H)	50 (1H)	50 25 (1H) (1E)		50 (1H)	50 (1H)			
Capacitance (Capacitance part numbering code) and T (mm) Dimension (T Dimension part numbering code)											
0.50pF(R50)	0.50 (5)										
0.75pF(R75)	0.50 (5)										
1.0pF(1R0)	0.50 (5)										
2.0pF(2R0)	0.50 (5)										
3.0pF(3R0)	0.50 (5)	0.50 (5)	0.50 (5)	0.50(5)			0.50 (5)	0.50 (5)			
4.0pF(4R0)	0.50 (5)	0.50 (5)	0.50 (5)	0.50(5)			0.50 (5)	0.50 (5)			
5.0pF(5R0)	0.50 (5)	0.50 (5)	0.50 (5)	0.50(5)			0.50(5)	0.50 (5)			
6.0pF(6R0)	0.50 (5)	0.50 (5)	0.50 (5)	0.50(5)			0.50(5)	0.50 (5)			
7.0pF(7R0)	0.50 (5)	0.50 (5)	0.50 (5)	0.50(5)			0.50(5)	0.50 (5)			
8.0pF(8R0)	0.50 (5)	0.50 (5)	0.50 (5)	0.50(5)			0.50(5)	0.50 (5)			
9.0pF(9R0)	0.50 (5)	0.50 (5)	0.50 (5)	0.50(5)			0.50(5)	0.50 (5)			
10pF(100)	0.50 (5)	0.50 (5)	0.50 (5)	0.50(5)			0.50(5)	0.50 (5)			
12pF(120)	0.50 (5)	0.50 (5)	0.50 (5)	0.50(5)			0.50(5)	0.50 (5)			
15pF(150)	0.50 (5)	0.50 (5)	0.50 (5)	0.50(5)			0.50(5)	0.50 (5)			
18pF(180)	0.50 (5)	0.50 (5)	0.50 (5)	0.50(5)			0.50(5)	0.50 (5)			
22pF(220)	0.50(5)	0.50(5)	0.50 (5)	0.50(5)			0.50(5)	0.50(5)			
27pF(270)	0.50 (5)	0.50(5)	0.50 (5)	0.50(5)			0.50(5)	0.50(5)			
33pF(330)	0.50(5)		0.50(5)	0.50(5)			0.50(5)	0.50(5)			





Dart Number		Dimensions (mm)						
Part Number	L	W	Т	е	g min.			
GRM155	1.0 ± 0.05	0.5 ± 0.05	0.5 ±0.05	0.15 to 0.3	0.4			
GRM188*	1.6 ±0.1	0.8 ±0.1	0.8 ±0.1	0.2 to 0.5	0.5			
GRM216			0.6 ±0.1		0.7			
GRM219	20+01	1.25 ±0.1 0.85 1.0 + 1.25	0.85 ±0.1	0.2 to 0.7				
GRM21A	2.0 ±0.1		1.0 +0/-0.2					
GRM21B			1.25 ±0.1					
GRM316			0.6 ±0.1					
GRM319	3.2 ±0.15	1.6 ±0.15	0.85 ±0.1	0.2 to 0.9	1 5			
GRM31M			1.15 ±0.1	0.3 10 0.8	1.5			
GRM31C	3.2 ±0.2	1.6 ±0.2	1.6 ±0.2					

* Bulk Case : 1.6 ±0.07(L)×0.8 ±0.07(W)×0.8 ±0.07(T)

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Dimensions (mm)

1.0 ±0.05 0.5 ±0.05 0.25 ±0.05 0.1 to 0.3

т

е

g min.

0.4

W

L.

Thin Type (Flow/Reflow)

- Features
- 1. This series is suited to flow and reflow soldering. Capacitor terminations are made of metal highly resistant to migration.
- 2. Large capacitance values enable excellent bypass effects to be realized.
- 3. Its thin package makes this series ideally suited for the production of small electronic products and for mounting underneath ICs.

Applications

Thin equipment such as IC cards

Temperature Compensating Type

Part Number	TC Code (Standard)	Rated Voltage (Vdc)	Capacitance (pF)	Length L (mm)	Width W (mm)	Thickness T (mm)
GRM15X5C1H1R0CDB4	COG (EIA)	50	1.0 ±0.25pF	1.00	0.50	0.25
GRM15X5C1H2R0CDB4	COG (EIA)	50	2.0 ±0.25pF	1.00	0.50	0.25
GRM15X5C1H3R0CDB4	COG (EIA)	50	3.0 ±0.25pF	1.00	0.50	0.25
GRM15X5C1H4R0CDB4	COG (EIA)	50	4.0 ±0.25pF	1.00	0.50	0.25
GRM15X5C1H5R0CDB4	COG (EIA)	50	5.0 ±0.25pF	1.00	0.50	0.25
GRM15X5C1H6R0DDB4	COG (EIA)	50	6.0 ±0.5pF	1.00	0.50	0.25
GRM15X5C1H7R0DDB4	COG (EIA)	50	7.0 ±0.5pF	1.00	0.50	0.25
GRM15X5C1H8R0DDB4	COG (EIA)	50	8.0 ±0.5pF	1.00	0.50	0.25
GRM15X5C1H9R0DDB4	COG (EIA)	50	9.0 ±0.5pF	1.00	0.50	0.25
GRM15X5C1H100JDB4	COG (EIA)	50	10 ±5%	1.00	0.50	0.25
GRM15X5C1H120JDB4	COG (EIA)	50	12 ±5%	1.00	0.50	0.25
GRM15X5C1H150JDB4	COG (EIA)	50	15 ±5%	1.00	0.50	0.25
GRM15X5C1H180JDB4	COG (EIA)	50	18 ±5%	1.00	0.50	0.25
GRM15X5C1H220JDB4	COG (EIA)	50	22 ±5%	1.00	0.50	0.25
GRM15X5C1H270JDB4	COG (EIA)	50	27 ±5%	1.00	0.50	0.25
GRM15X5C1H330JDB4	COG (EIA)	50	33 ±5%	1.00	0.50	0.25
GRM15X5C1H390JDB4	COG (EIA)	50	39 ±5%	1.00	0.50	0.25
GRM15X5C1H470JDB4	COG (EIA)	50	47 ±5%	1.00	0.50	0.25
GRM15X5C1H560JDB4	COG (EIA)	50	56 ±5%	1.00	0.50	0.25
GRM15X5C1H680JDB4	COG (EIA)	50	68 ±5%	1.00	0.50	0.25
GRM15X5C1H820JDB4	COG (EIA)	50	82 ±5%	1.00	0.50	0.25
GRM15X5C1H101JDB4	COG (EIA)	50	100 ±5%	1.00	0.50	0.25
GRM15X5C1E121JDB4	COG (EIA)	25	120 ±5%	1.00	0.50	0.25
GRM15X5C1E151JDB4	COG (EIA)	25	150 ±5%	1.00	0.50	0.25
GRM15X5C1E181JDB4	COG (EIA)	25	180 ±5%	1.00	0.50	0.25
GRM15X5C1E221JDB4	COG (EIA)	25	220 ±5%	1.00	0.50	0.25

Part Number

GRM15X

High Dielectric Constant Type

Part Number	TC Code (Standard)	Rated Voltage (Vdc)	Capacitance (pF)	Length L (mm)	Width W (mm)	Thickness T (mm)
GRM15XR71H221KA86	X7R (EIA)	50	220 ±10%	1.00	0.50	0.25
GRM15XR71H331KA86	X7R (EIA)	50	330 ±10%	1.00	0.50	0.25
GRM15XR71H471KA86	X7R (EIA)	50	470 ±10%	1.00	0.50	0.25



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Part Number	TC Code (Standard)	Rated Voltage (Vdc)	Capacitance (pF)	Length L (mm)	Width W (mm)	Thickness T (mm)
GRM15XR71H681KA86	X7R (EIA)	50	680 ±10%	1.00	0.50	0.25
GRM15XR71H102KA86	X7R (EIA)	50	1000 ±10%	1.00	0.50	0.25
GRM15XR71H152KA86	X7R (EIA)	50	1500 ±10%	1.00	0.50	0.25
GRM15XR71E182KA86	X7R (EIA)	25	1800 ±10%	1.00	0.50	0.25
GRM15XR71E222KA86	X7R (EIA)	25	2200 ±10%	1.00	0.50	0.25
GRM15XR71C332KA86	X7R (EIA)	16	3300 ±10%	1.00	0.50	0.25
GRM15XR71C472KA86	X7R (EIA)	16	4700 ±10%	1.00	0.50	0.25
GRM15XR71C682KA86	X7R (EIA)	16	6800 ±10%	1.00	0.50	0.25



			Specifi				
No.	lte	em	Temperature Compensating Type	High Dielectric Type	-	Test Method	
1	Operating Temperat) ure	−55 to +125℃	R6 : −55 to +85℃ R7 : −55 to +125℃ E4 : +10 to +85℃ F5 : −30 to +85℃			
2	2 Rated Voltage		See the previous page.		The rated voltage is defined as the maximum voltage which may be applied continuously to the capacitor. When AC voltage is superimposed on DC voltage, V ^{P-P} or V ^{O-P} , whichever is larger, should be maintained within the rated voltage range		
3	Appearar	ice	No defects or abnormalities		Visual inspection		
4	Dimensio	ns	Within the specified dimensions		Using calipers on mi	crometer	
5	5 Dielectric Strength		h No defects or abnormalities		No failure should be observed when *300% of the rated voltage (C0 Δ to U2J and SL) or *250% of the rated voltage (X5R, X7R, Z5U and Y5V) is applied between the terminations for 1 to 5 seconds, provided the charge/discharge current is less than 50mA. *200% for 500V		
6	Insulation Resistanc	i ce	More than 10,000M Ω or 500 Ω •	F (Whichever is smaller)	The insulation resistance should be mea voltage not exceeding the rated voltage max. and within 2 minutes of charging.		ured with a DC : 25℃ and 75%RH
7	Capacita	nce	Within the specified tolerance		The capacitance/Q/I	D.F. should be measu ae shown in the table.	red at 25℃ at the
				[R6, R7]	Item Cha	ar. Frequency	Voltage
	Q/ Dissipation Factor (D.F.)			W.V. : 25 Vinit. : 0.025 Max. W.V. : 16/10V : 0.035 max. W.V. : 6.3V 0.05 max (C<3.3 µE)	∆C to 7U, 1X (1000pF and below)	1±0.1MHz	0.5 to 5Vrms
8			30pFmin. : Q≧1000 30pFmax. : Q≧400+20C	0.1max.(C≥3.3µF) [E4]	ΔC to 7U, 1X (more than 1000pF)	1±0.1kHz	1±0.2Vrms
			C : Nominal Capacitance (pF)	[F5] W.V. : 25Vmin.	R6, R7, F5 (10µF and below) 1±0.1kHz	1±0.2Vrms
				: 0.05max.(C<0.10µF) : 0.09max.(C≧0.10µF) W.V. : 16V/10V : 0.125max.	R6, R7, F5 (more than 10μF) 120±24Hz	0.5±0.1Vrms
				W.V. : 6.3Vmax. : 0.15max.	E4	1±0.1kHz	0.5±0.05Vrms
		Capacitance Change	Within the specified tolerance (Table A)	R6 : Within $\pm 15\%$ (-55 to +85°C) R7 : Within $\pm 15\%$ (-55 to +125°C) E4 : Within +22/-56% (+10 to +85°C) F5 : Within +22/-82% (-30 to +85°C)	The capacitance change should be measured a each specified temperature stage. (1) Temperature Compensating Type The temperature coefficient is determined usin Capacitance measured in step 3 as a reference When cycling the temperature sequentially from 5 ($CO\Delta$: +25°C to +125°C : other temp. coeffs. +85°C) the capacitance should be within the sp for the temperature coefficient and capacitance		ured after 5 min. at using the rence. y from step 1 through effs. : +25°c to he specified tolerance tance change as
	Capacitance	Temperature	Within the specified tolerance		Table A. The capacitance drift between the maximu 1, 3 and 5 by the cap	t is calculated by dividum and minimum mea	ding the differences sured values in steps p 3.
9	Characteristics	Coefficient	(Table A)		Step	lemperat 25+	2
					2	-55±3 (for ∆C to -30±3 (f 10±3 (fo	7U/1X/R6/R7) for F5) or E4)
					3	25±	2
					4	125±3 (for 85±3 (for o	∆C/R7) ther TC)
		Capacitance	(Whichever is larger.)		5	25±	2
		Drift	(Whichever is larger.) *Does not apply to 1X/25V		 (2) High Dielectric Constant Type The ranges of capacitance change compared with the above 25°C value over the temperature ranges shown in the table should be within the specified ranges. 		



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			Specifi	cations			
No.	lte	m	Temperature Compensating Type	High Dielectric Type	Test Method		
10	10 Adhesive Strength of Termination		No removal of the terminations	or other defect should occur.	Solder the capacitor to the test jig (glass epoxy board) shown in Fig. 1 using a eutectic solder. Then apply 10N* force in parallel with the test jig for 10±1sec. The soldering should be done either with an iron or using the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock. *2N (GR□03) 5N (GR□15, GRM18) Image: solder resist Image: solder resist		
		Appearance	No defects or abnormalities				
		Capacitance	Within the specified tolerance				
11	Vibration Resistance	Q/D.F.	30pFmin. : Q≧1000 30pFmax. : Q≧400+20C C : Nominal Capacitance (pF)	$\begin{array}{l} [R6,R7] \\ W.V.: 25Vmin.: 0.025max. \\ W.V.: 16/10V: 0.035max. \\ W.V.: 6.3V: \\ 0.05max. (C{<}3.3\muF) \\ 0.1max. (C{\geq}3.3\muF) \\ [E4] \\ W.V.: 25Vmin.: 0.025max. \\ [F5] \\ W.V.: 25Vmin. \\ : 0.05max. (C{<}0.10\muF) \\ : 0.09max. (C{\geq}0.10\muF) \\ W.V.: 16V/10V: 0.125max. \\ \\ W.V.: 6.3Vmax.: 0.15max. \end{array}$	Solder the capacitor to the test jig (glass epoxy board) in the same manner and under the same conditions as (10). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 55Hz. The frequency range, from 10 to 55Hz and return to 10Hz, should be traversed in approximately 1 minute. This motion should be applied for a period of 2 hours in each of 3 mutually perpendicular directions (total of 6 hours).		
			No crack or marked defect shou	lld occur.	Solder the capacitor on the test jig (glass epoxy board) shown in Fig. 2 using a eutectic solder. Then apply a force in the direction shown in Fig. 3. The soldering should be done either with an iron or using the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock.		
12	12 Deflection		Type a GR□03 0.3 GR□15 0.4 GRM21 1.2 GRM31 2.2 GRM32 2.2 GRM43 3.5 GRM55 4.5		20 50 Pressurizing speed : 1.0mm/sec. Pressurize Pressurize Flexure : ≤1 Capacitance meter 45 45 45		



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			Specifi	cations					
No.	lte	em	Temperature Compensating Type	High Dielectric Type		Test	Method		
13	Solderabi Terminati	llity of on	75% of the terminations are to b continuously.	be soldered evenly and	nly and Immerse the capacitor in a solution or rosin (JIS-K-5902) (25% rosin in weig Preheat at 80 to 120°C for 10 to 30 see immerse in eutectic solder solution for 230±5°C.		lution of in weigh to 30 sec lution for	ethanol (JIS-K- t proportion). onds. After pre 2±0.5 seconds	-8101) and cheating, s at
			The measured and observed ch specifications in the following ta						
		Appearance	No marking defects						
		Capacitance Change	Within $\pm 2.5\%$ or ± 0.25 pF (Whichever is larger)	R6, R7 : Within ±7.5% E4, F5 : Within ±20%	Preheat the capacitor at 120 to 150°C for 1 minute.			270+5℃	
14	Resistance to Soldering Heat	Q/D.F. 30pFmin. : Q≥1000 30pFmax. : Q≥400+20C C : Nominal Capacitance (pF)		$[R6, R7] \\ W.V.: 25Vmin.: 0.025max. \\ W.V.: 16/10V: 0.035max. \\ W.V.: 6.3V: \\ 0.05max. (C<3.3\muF) \\ 0.1max. (C\geq3.3\muF) \\ [E4] \\ W.V.: 25Vmin.: 0.025max. \\ [F5] \\ W.V.: 25Vmin. \\ : 0.05max. (C<0.10\muF) \\ : 0.09max. (C \geq 0.10\muF) \\ W.V.: 16V/10V: 0.125max. \\ W.V.: 6.3Vmax.: 0.15max. \\ W.V. \\ \end{tabular}$	for 10±0.5 seconds. Let sit at room temperature for 24±2 hot (temperature compensating type) or 48±4 hours (high dielect constant type), then measure. •Initial measurement for high dielectric constant type Perform a heat treatment at 150 ±18°C for one hour and the let sit for 48±4 hours at room temperature. Perform the initial measurement. *Preheating for GRM32/43/55 <u>Step Temperature Time</u> 1 100°C to 120°C 1 min. 2 170°C to 200°C 1 min.				24±2 hours h dielectric and then n. n.
		I.R.	More than 10,000M Ω or 500 Ω •	F (Whichever is smaller)					
		Dielectric Strength	No failure						
			The measured and observed ch specifications in the following ta	aracteristics should satisfy the ble.					
		Appearance	No marking defects						
		Capacitance Change	Within $\pm 2.5\%$ or ± 0.25 pF (Whichever is larger)	R6, R7 : Within ±7.5% E4, F5 : Within ±20%	Fix the capacite	or to the suppo	rting jig ii (10) Pe	n the same ma	inner and
				[R6, R7] W.V. : 25Vmin. : 0.025max. W.V. : 16/10V : 0.035max. W.V. : 6.3V	according to th table. Let sit fo or 48±4 hour (temperature, th	e four heat trea r 24±2 hours (1 high dielectric o hen measure.	atments li temperationstant	sted in the folloure compensatives at room	owing iting type)
	Tomporaturo			0.05max. (C<3.3µF)	Step	1	2	3	4
15	Cycle	Q/D.F.	30pFmin. : Q≧1000 30pFmax. : Q≧400+20C C : Nominal Capacitance (pE)	0.1max. (C≥3.3µF) [E4] W.V. : 25Vmin. : 0.025max.	Temp. (℃)	Min. Operating Temp.+0/-3	Room Temp.	Max. Operating Temp.+3/-0	Room Temp.
			C. Norminal Capacitance (pr)	[F5]	Time (min.)	30±3	2 to 3	30±3	2 to 3
				 W.V.: 25Vmin. : 0.05max. (C<0.10μF) : 0.09max. (C≥0.10μF) W.V.: 16V/10V : 0.125max. W.V.: 6.3Vmax.: 0.15max. 	 Initial measurement for high dielectric constant type Perform a heat treatment at 150 ±18℃ for one hour and then let sit for 48±4 hours at room temperature. Perform the initial measurement. 				
		I.R.	More than 10,000M Ω or 500 Ω •	F (Whichever is smaller)					
		Dielectric Strength No failure							



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			Specifi	cations			
No.	Ite	m	Temperature Compensating Type	High Dielectric Type	Test Method		
			The measured and observed ch specifications in the following ta	aracteristics should satisfy the ble.			
		Appearance	No marking defects				
		Capacitance Change	Within $\pm 5\%$ or ± 0.5 pF (Whichever is larger)	R6, R7 : Within ±12.5% E4, F5 : Within ±30%			
16	Humidity Steady State	Q/D.F.	30pF and over : Q≥350 10pF and over 30pF and below : Q≥275+5C/2 10pF and below : Q≥200+10C C : Nominal Capacitance (pF)	[R6, R7] W.V. : 25Vmin. : 0.05max. W.V. : 16/10V : 0.05max. W.V. : 6.3V 0.075max. (C<3.3µF) 0.125max. (C≥3.3µF) [E4] W.V. : 25Vmin. : 0.05max. [F5] W.V. : 25Vmin. : 0.075max. (C<0.10µF) : 0.125max. (C≥0.10µF) W.V. : 16V/10V : 0.15max. W.V. : 6.3Vmax. : 0.2max.	Let the capacitor sit at 40±2°C and 90 to 95% humidity for 500±12 hours. Remove and let sit for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type) at room tem- perature, then measure.		
		I.R.	More than 1,000M Ω or 50 Ω • F	(Whichever is smaller)	•		
		Dielectric Strength	C No failure				
			The measured and observed ch specifications in the following ta	aracteristics should satisfy the ble.			
		Appearance	No marking defects				
		Capacitance Change	Within ±7.5% or ±0.75pF (Whichever is larger)	R6, R7 : Within ±12.5% E4 : Within ±30% F5 : Within ±30% [W.V. : 10Vmax.] F5 : Within +30/-40%			
17	Humidity Load	Q/D.F.	30pF and over : Q≥200 30pF and below : Q≥100+10C/3 C : Nominal Capacitance (pF)	$[R6, R7] \\ W.V. : 25Vmin. : 0.05max. \\ W.V. : 16/10V : 0.05max. \\ W.V. : 6.3V \\ 0.075max. (C<3.3\muF) \\ 0.125max. (C\geq3.3\muF) \\ [E4] \\ W.V. : 25Vmin. : 0.05max. \\ [F5] \\ W.V. : 25Vmin. \\ : 0.075max. (C<0.10\muF) \\ : 0.125max. (C\geq0.10\muF) \\ W.V. : 16V/10V : 0.15max. \\ W.V. : 6.3Vmax. : 0.2max. \\ W.V. : 0.2max \\ W.V. : 0.2max \\ W.V. : 0.2max \\ W.V. : $	 Apply the rated voltage at 40±2°C and 90 to 95% humidity for 500±12 hours. Remove and let sit for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type) at room temperature, then measure. The charge/discharge current is less than 50mA. Initial measurement for F5/10V max. Apply the rated DC voltage for 1 hour at 40±2°C. Remove and let sit for 48±4 hours at room temperature. Perform initial measurement. 		
		I.R.	More than 500MΩ or 25Ω • F (V	Vhichever is smaller)			
		Dielectric Strength	No failure				



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			Specifi	cations			
No.	Item		Temperature Compensating Type	High Dielectric Type	Test Method		
			The measured and observed characteristics should satisfy the specifications in the following table.				
		Appearance	No marking defects				
		Capacitance Change	Within ±3% or ±0.3pF (Whichever is larger)	R6, R7 : Within ±12.5% E4 : Within ±30% F5 : Within ±30% (Cap<1.0μF) F5 : Within +30/−40% (Cap≧1.0μF)	Apply 200% of the rated voltage for 1000±12 hours at the		
18	High Temperature Load	Q/D.F.	30pF and over : Q≥350 10pF and over 30pF and below : Q≥275+5C/2 10pF and below : Q≥200+10C C : Nominal Capacitance (pF)	$ \begin{array}{l} [{\sf R6}, {\sf R7}] \\ {\sf W.V.} : 25{\sf Vmin.} : 0.05{\sf max.} \\ {\sf W.V.} : 16/10{\sf V}: 0.05{\sf max.} \\ {\sf W.V.} : 6.3{\sf V} \\ 0.075{\sf max.} ({\sf C}{<}3.3\mu{\sf F}) \\ 0.125{\sf max.} ({\sf C}{\geq}3.3\mu{\sf F}) \\ [{\sf E4}] \\ {\sf W.V.} : 25{\sf Vmin.} : 0.05{\sf max} \\ [{\sf F5}] \\ {\sf W.V.} : 25{\sf Vmin.} \\ : 0.075{\sf max.} ({\sf C}{<}0.10\mu{\sf F}) \\ : 0.125{\sf max.} ({\sf C}{\geq}0.10\mu{\sf F}) \\ : 0.125{\sf max.} ({\sf C}{\geq}0.10\mu{\sf F}) \\ {\sf W.V.} : 16{\sf V}/10{\sf V}: 0.15{\sf max.} \\ \\ {\sf W.V.} : 6.3{\sf Vmax.}: 0.2{\sf max.} \\ \end{array} $	maximum operating temperature ±3°C. Let sit for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type) at room temperature, then measure. The charge/discharge current is less than 50mA. •Initial measurement for high dielectric constant type. Apply 200% of the rated DC voltage for one hour at the maximum operating temperature ±3°C. Remove and let sit for 48±4 hours at room temperature. Perform initial measurement. *150% for 500V and C≥10µF		
		I.R.	More than 1,000M Ω or 50 Ω •F (, Whichever is smaller)			
		Dielectric Strength	No failure				

Table A

		Capacitance Change from 25°C (%)						
Char. Code	Nominal Values (ppm/℃)*	_!	-55 -30		30	-10		
		Max.	Min.	Max.	Min.	Max.	Min.	
5C	0 ± 30	0.58	-0.24	0.40	-0.17	0.25	-0.11	
6C	0 ± 60	0.87	-0.48	0.59	-0.33	0.38	-0.21	
6P	-150 ± 60	2.33	0.72	1.61	0.50	1.02	0.32	
6R	-220 ± 60	3.02	1.28	2.08	0.88	1.32	0.56	
6S	-330 ± 60	4.09	2.16	2.81	1.49	1.79	0.95	
6T	-470 ± 60	5.46	3.28	3.75	2.26	2.39	1.44	
7U	-750 ±120	8.78	5.04	6.04	3.47	3.84	2.21	
1X	+350 to -1000	-	_	-	-	-	-	

*Nominal values denote the temperature coefficient within a range of 25℃ to 125℃ (for △C)/85℃ (for other TC).



Chip Monolithic Ceramic Capacitors

muRata

for Reflow Soldering GRM32/43/55 Series

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Features

- 1. Terminations are made of metal highly resistant to migration.
- 2. The GRM series is a complete line of chip ceramic capacitors in 10V, 16V, 25V, 50V, 100V and 200V ratings.

These capacitors have temperature characteristics ranging from C0G to Y5V.

- 3. This series consists of type LxWxT: 3.2x2.5x0.85mm to LxWxT: 5.7x5.0x2.5mm. These are suited to only reflow soldering.
- 4. Stringent dimensional tolerances allow highly reliable, high speed automatic chip placement on PCBs.
- 5. The GRM series is available in paper or plastic embossed tape and reel packaging for automatic placement.

Applications

General electronic equipment

Temperature Compensating Type GRM32/43/55 Series

Part Number	TC Code (Standard)	Rated Voltage (Vdc)	Capacitance (pF)	Length L (mm)	Width W (mm)	Thickness T (mm)
GRM32N5C2D561JV01	COG (EIA)	200	560 ±5%	3.20	2.50	1.35
GRM32N5C2D681JY21	COG (EIA)	200	680 ±5%	3.20	2.50	1.35
GRM32N5C2D821JY21	COG (EIA)	200	820 ±5%	3.20	2.50	1.35
GRM32N5C2D102JY21	COG (EIA)	200	1000 ±5%	3.20	2.50	1.35
GRM43R5C2D122JV01	COG (EIA)	200	1200 ±5% 4.50		3.20	1.80
GRM43R5C2D152JV01	COG (EIA)	200	1500 ±5% 4.50		3.20	1.80
GRM43R5C2D182JY21	COG (EIA)	200	1800 ±5%	4.50	3.20	1.80
GRM43R5C2D222JY21	COG (EIA)	200	2200 ±5%	4.50	3.20	1.80
GRM43R5C2D272JY21	COG (EIA)	200	2700 ±5%	4.50	3.20	1.80
GRM55N5C2D332JY21	COG (EIA)	200	3300 ±5%	5.70	5.00	1.35
GRM55R5C2D392JY21	COG (EIA)	200	3900 ±5% 5.70		5.00	1.80
GRM55R5C2D472JY21	COG (EIA)	200	4700 ±5% 5.70		5.00	1.80
GRM55R5C2D562JY21	COG (EIA)	200	5600 ±5% 5.70 5.0		5.00	1.80
GRM32N1X2D152JV01	SL (JIS)	200	1500 ±5% 3.20		2.50	1.35
GRM43N1X2D182JV01	SL (JIS)	200	1800 ±5%	4.50	3.20	1.35
GRM43N1X2D222JV01	SL (JIS)	200	2200 ±5%	4.50	3.20	1.35
GRM43R1X2D272JV01	SL (JIS)	200	2700 ±5%	4.50	3.20	1.80
GRM43R1X2D332JV01	SL (JIS)	200	3300 ±5%	4.50	3.20	1.80
GRM43R1X2D392JV01	SL (JIS)	200	3900 ±5%	4.50	3.20	1.80
GRM55N1X2D472JV01	SL (JIS)	200	4700 ±5%	5.70	5.00	1.35
GRM55R1X2D562JV01	SL (JIS)	200	5600 ±5%	5.70	5.00	1.80
GRM55R1X2D682JV01	SL (JIS)	200	6800 ±5%	5.70	5.00	1.80
GRM55R1X2D822JV01	SL (JIS)	200	8200 ±5%	5.70	5.00	1.80
GRM32N1X2A562JZ01	SL (JIS)	100	5600 ±5%	3.20	2.50	1.35
GRM32N1X2A682JZ01	SL (JIS)	100	6800 ±5%	3.20	2.50	1.35
GRM43N1X2A822JZ01	SL (JIS)	100	8200 ±5%	4.50	3.20	1.35
GRM43R1X2A103JZ01	SL (JIS)	100	10000 ±5%	4.50	3.20	1.80





Continued from the preceding page.

Part Number	TC Code (Standard)	Rated Voltage (Vdc)	Capacitance (pF)	Length L (mm)	Width W (mm)	Thickness T (mm)
GRM43R1X2A123JZ01	SL (JIS)	100	12000 ±5%	4.50	3.20	1.80
GRM43R1X2A153JZ01	SL (JIS)	100	15000 ±5%	4.50	3.20	1.80
GRM55M1X2A183JZ01	SL (JIS)	100	18000 ±5%	5.70	5.00	1.15
GRM55N1X2A223JZ01	SL (JIS)	100	22000 ±5%	5.70	5.00	1.35
GRM55R1X2A273JZ01	SL (JIS)	100	27000 ±5%	5.70	5.00	1.80
GRM55R1X2A333JZ01	SL (JIS)	100	33000 ±5%	5.70	5.00	1.80
GRM55R1X2A393JZ01	SL (JIS)	100	39000 ±5%	5.70	5.00	1.80
GRM32N1X1H103JZ01	SL (JIS)	50	10000 ±5%	3.20	2.50	1.35
GRM32N1X1H123JZ01	SL (JIS)	50	12000 ±5%	3.20	2.50	1.35
GRM43R1X1H153JZ01	SL (JIS)	50	15000 ±5%	4.50	3.20	1.80
GRM55M1X1H183JZ01	SL (JIS)	50	18000 ±5%	5.70	5.00	1.15
GRM55N1X1H223JZ01	SL (JIS)	50	22000 ±5%	5.70	5.00	1.35
GRM55R1X1H273JZ01	SL (JIS)	50	27000 ±5%	5.70	5.00	1.80
GRM55R1X1H333JZ01	SL (JIS)	50	33000 ±5%	5.70	5.00	1.80
GRM55R1X1H393JZ01	SL (JIS)	50	39000 ±5%	5.70	5.00	1.80

High Dielectric Constant Type Type GRM32 Series (3.20x2.50mm)

Part Number	TC Code (Standard)	Rated Voltage (Vdc)	Capacitance	Length L (mm)	Width W (mm)	Thickness T (mm)
GRM32ER61A106KC01	X5R (EIA)	10	10μF ±10%	3.20	2.50	2.50
GRM32NR72A683KA01	X7R (EIA) 100 68000pF ±10%		68000pF ±10%	3.20	2.50	1.35
GRM32NR72A104KA01	X7R (EIA)	100	0.10μF ±10%	3.20	2.50	1.35
GRM32ER72A105KA01	RM32ER72A105KA01 X7R (EIA) 100 1.0μF ±10%		3.20	2.50	2.50	
GRM32NR71H684KA01	X7R (EIA)	50	0.68μF ±10%	3.20	2.50	1.35
GRM32RR71H105KA01	X7R (EIA)	50	1.0μF ±10%	3.20	2.50	1.80
GRM32RR71E225KC01	X7R (EIA)	25	2.2μF ±10%	3.20	2.50	1.80
GRM32MR71C225KC01	X7R (EIA)	16	2.2μF ±10%	3.20	2.50	1.15
GRM32NR71C335KC01	X7R (EIA)	16	3.3μF ±10%	3.20	2.50	1.35
GRM32RR71C475KC01	X7R (EIA)	16	4.7μF ±10%	3.20	2.50	1.80
GRM32ER71H475KA88	X7R (EIA)	16	4.7μF ±10%	3.20	2.50	2.50
GRM32NF52A104ZA01	Y5V (EIA)	100	0.10µF +80/-20%	3.20	2.50	1.35
GRM32RF51H105ZA01	Y5V (EIA)	50	1.0µF +80/-20%	3.20	2.50	1.8
GRM32DF51H106ZA01	Y5V (EIA)	50	10µF +80/-20%	3.20	2.50	2.00
GRM329F51E475ZA01	Y5V (EIA)	25	4.7µF +80/-20%	3.20	2.50	0.85
GRM32NF51E106ZA01	Y5V (EIA)	25	10μF +80/-20%	3.20	2.50	1.35
GRM32NF51C106ZA01	Y5V (EIA)	16	10μF +80/-20%	3.20	2.50	1.35

High Dielectric Constant Type Type GRM43 Series (4.50x3.20mm)

Part Number	TC Code (Standard)	Rated Voltage (Vdc)	Capacitance (μF)	Length L (mm)	Width W (mm)	Thickness T (mm)
GRM43RR72A154KA01	X7R (EIA)	100	0.15 ±10%	4.50	3.20	1.80
GRM43RR72A224KA01	X7R (EIA)	100	0.22 ±10%	4.50	3.20	1.80
GRM43DR72A474KA01	X7R (EIA)	100	0.47 ±10%	4.50	3.20	2.00
GRM43ER72A225KA01	X7R (EIA)	100	2.2 ±10%	4.50	3.20	2.50
GRM43ER71H225KA01	X7R (EIA)	50	2.2 ±10%	4.50	3.20	2.50



2

High Dielectric Constant Type Type GRM55 Series (5.70x5.00mm)

Part Number	TC Code (Standard)	Rated Voltage (Vdc)	Capacitance (μF)	Length L (mm)	Width W (mm)	Thickness T (mm)
GRM55DR61H106KA01	X5R (EIA)	50	10.0 ±10%	5.70	5.00	2.00
GRM55DR72A105KA01	X7R (EIA)	100	1.0 ±10%	5.70	5.00	2.00
GRM55ER72A475KA01	X7R (EIA)	100	4.7 ±10%	5.70	5.00	2.50
GRM55RR71H105KA01	X7R (EIA)	50	1.0 ±10%	5.70	5.00	1.80
GRM55RR71H155KA01	X7R (EIA)	50	1.5 ±10%	5.70	5.00	1.80
GRM55ER71H475KA01	X7R (EIA)	50	4.7 ±10%	5.70	5.00	2.50
GRM55RF52A474ZA01	Y5V (EIA)	100	0.47 +80/-20%	5.70	5.00	1.80



			Specifi	cations			
No.	lte	em	Temperature Compensating Type	High Dielectric Type	-	Test Method	
1	Operating Temperat) ure	−55 to +125℃	R6 : −55 to +85℃ R7 : −55 to +125℃ E4 : +10 to +85℃ F5 : −30 to +85℃			
2	Rated Vo	ltage	See the previous page.	The rated voltage is defined as the maximum voltage which may be applied continuously to the capacitor. When AC voltage is superimposed on DC voltage, V ^{P-P} or V ^{O-P} , whichever is larger, should be maintained within the rated voltage range.			
3	Appearar	ice	No defects or abnormalities		Visual inspection		
4	Dimensio	ns	Within the specified dimensions		Using calipers on mi	crometer	
5	Dielectric Strength No		No defects or abnormalities		No failure should be observed when *300% of the rated voltage (C0 Δ to U2J and SL) or *250% of the rated voltage (X5R, X7R, Z5U and Y5V) is applied between the terminations for 1 to 5 seconds, provided the charge/discharge current is less than 50mA. *200% for 500V		
6	Insulation Resistanc	i ce	More than 10,000M Ω or 500 Ω •	F (Whichever is smaller)	The insulation resist voltage not exceedir max. and within 2 m	ance should be meas ng the rated voltage at inutes of charging.	ured with a DC : 25℃ and 75%RH
7	Capacita	nce	Within the specified tolerance		The capacitance/Q/I	D.F. should be measu ae shown in the table.	red at 25℃ at the
				[R6, R7]	Item Cha	ar. Frequency	Voltage
	Q/ Dissipation Factor (D.F.)			W.V. : 25Vmin. : 0.025max. W.V. : 16/10V : 0.035max. W.V. : 6.3V	∆C to 7U, 1X (1000pF and below)	1±0.1MHz	0.5 to 5Vrms
8			30pFmin. : Q≧1000 30pFmax. : Q≧400+20C	0.1max.(C≥3.3µF) [E4]	ΔC to 7U, 1X (more than 1000pF)	1±0.1kHz	1±0.2Vrms
			C : Nominal Capacitance (pF)	[F5] W.V. : 25Vmin.	R6, R7, F5 (10µF and below) 1±0.1kHz	1±0.2Vrms
				: 0.05max.(C<0.10µF) : 0.09max.(C≧0.10µF) W.V. : 16V/10V : 0.125max.	R6, R7, F5 (more than 10μF) 120±24Hz	0.5±0.1Vrms
				W.V. : 6.3Vmax. : 0.15max.	E4	1±0.1kHz	0.5±0.05Vrms
	Capacitance Change		Within the specified tolerance (Table A)	R6 : Within $\pm 15\%$ (-55 to +85°C) R7 : Within $\pm 15\%$ (-55 to +125°C) E4 : Within +22/-56% (+10 to +85°C) F5 : Within +22/-82% (-30 to +85°C)	The capacitance change should be measured each specified temperature stage. (1) Temperature Compensating Type The temperature coefficient is determined usin Capacitance measured in step 3 as a reference When cycling the temperature sequentially fro $5 (C0\Delta : +25^{\circ}C to +125^{\circ}C : other temp. coeffs.$ +85 ^o C) the capacitance should be within the s		ured after 5 min. at using the rence. y from step 1 through effs. : +25°c to he specified tolerance tance change as
	Capacitance	Temperature	Within the specified tolerance		Table A. The capacitance drift between the maximu 1, 3 and 5 by the cap	t is calculated by dividum and minimum mea	ding the differences sured values in steps p 3.
9	Characteristics	Coefficient	(Table A)		Step	lemperat 25+	2
					2	-55±3 (for ∆C to -30±3 (f 10±3 (fo	7U/1X/R6/R7) for F5) or E4)
					3	25±	2
			Within $\pm 0.2\%$ or ± 0.05 pE		4	125±3 (for 85±3 (for o	∆C/R7) ther TC)
		Capacitance	(Whichever is larger.)		5	25±	2
			*Does not apply to 1X/25V		 (2) High Dielectric Constant Type The ranges of capacitance change compared with the above 25°C value over the temperature ranges shown in the table should be within the specified ranges. 		



Continued from the preceding page.

			Specifi	cations			
No.	lte	m	Temperature Compensating Type	High Dielectric Type	Test Method		
10	10 Adhesive Strength of Termination		No removal of the terminations	or other defect should occur.	Solder the capacitor to the test jig (glass epoxy board) shown in Fig. 1 using a eutectic solder. Then apply 10N* force in parallel with the test jig for 10±1sec. The soldering should be done either with an iron or using the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock. *2N (GR□03) 5N (GR□15, GRM18)		
	Appearance		No defects or abnormalities				
		Capacitance	Within the specified tolerance				
11	Vibration Resistance	Q/D.F.	30pFmin. : Q≧1000 30pFmax. : Q≧400+20C C : Nominal Capacitance (pF)	$\begin{array}{l} [R6,R7] \\ W.V.: 25Vmin.: 0.025max. \\ W.V.: 16/10V: 0.035max. \\ W.V.: 6.3V: \\ 0.05max. (C{<}3.3\muF) \\ 0.1max. (C{\geq}3.3\muF) \\ [E4] \\ W.V.: 25Vmin.: 0.025max. \\ [F5] \\ W.V.: 25Vmin. \\ : 0.05max. (C{<}0.10\muF) \\ : 0.09max. (C{\geq}0.10\muF) \\ W.V.: 16V/10V: 0.125max. \\ \\ W.V.: 6.3Vmax.: 0.15max. \end{array}$	Solder the capacitor to the test jig (glass epoxy board) in the same manner and under the same conditions as (10). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 55Hz. The frequency range, from 10 to 55Hz and return to 10Hz, should be traversed in approximately 1 minute. This motion should be applied for a period of 2 hours in each of 3 mutually perpendicular directions (total of 6 hours).		
			No crack or marked defect shou	lld occur.	Solder the capacitor on the test jig (glass epoxy board) shown in Fig. 2 using a eutectic solder. Then apply a force in the direction shown in Fig. 3. The soldering should be done either with an iron or using the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock.		
12	Deflection	ı	Type a GR□03 0.3 GR□15 0.4 GRM21 1.2 GRM31 2.2 GRM32 2.2 GRM43 3.5 GRM55 4.5		20 speed : 1.0mm/sec. Pressurize Pressurize Pressurize Flexure : ≤1R230 Capacitance meter 45Fig. 3		



Continued from the preceding page.

			Specifi	cations					
No.	lte	em	Temperature Compensating Type	High Dielectric Type		Test	Method		
13	Solderabi Terminati	llity of on	75% of the terminations are to b continuously.	be soldered evenly and	Immerse the ca rosin (JIS-K-59 Preheat at 80 t immerse in eut 230±5℃.	apacitor in a so 102) (25% rosin o 120°C for 10 ectic solder so	lution of in weigh to 30 sec lution for	ethanol (JIS-K- t proportion). onds. After pre 2±0.5 seconds	-8101) and cheating, s at
			The measured and observed ch specifications in the following ta	aracteristics should satisfy the ble.					
		Appearance	No marking defects						
		Capacitance Change	Within $\pm 2.5\%$ or ± 0.25 pF (Whichever is larger)	R6, R7 : Within ±7.5% E4, F5 : Within ±20%	Preheat the ca	pacitor at 120 t	o 150℃ f	or 1 minute. der solution at	270+5℃
14	Resistance to Soldering Heat	Q/D.F.	30pFmin. : Q≧1000 30pFmax. : Q≧400+20C C : Nominal Capacitance (pF)	$[R6, R7] \\ W.V.: 25Vmin.: 0.025max. \\ W.V.: 16/10V: 0.035max. \\ W.V.: 6.3V: \\ 0.05max. (C<3.3\muF) \\ 0.1max. (C\geq3.3\muF) \\ [E4] \\ W.V.: 25Vmin.: 0.025max. \\ [F5] \\ W.V.: 25Vmin. \\ : 0.05max. (C<0.10\muF) \\ : 0.09max. (C \geq 0.10\muF) \\ W.V.: 16V/10V: 0.125max. \\ W.V.: 6.3Vmax.: 0.15max. \\ W.V. \\ \end{tabular}$	for 10±0.5 seconds. Let sit at room temperature for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type), then measure. •Initial measurement for high dielectric constant type Perform a heat treatment at 150 ±18℃ for one hour and then let sit for 48±4 hours at room temperature. Perform the initial measurement. *Preheating for GRM32/43/55 Step Temperature 1 100℃ to 120℃ 2 170℃ to 200℃ 1 min.				
		I.R.	More than 10,000M Ω or 500 Ω •	F (Whichever is smaller)					
		Dielectric Strength	No failure						
			The measured and observed ch specifications in the following ta						
		Appearance	No marking defects						
		Capacitance Change	Within $\pm 2.5\%$ or ± 0.25 pF (Whichever is larger)	R6, R7 : Within ±7.5% E4, F5 : Within ±20%	Fix the capacite	or to the suppo	rting jig ii (10) Pe	n the same ma	inner and
				[R6, R7] W.V. : 25Vmin. : 0.025max. W.V. : 16/10V : 0.035max. W.V. : 6.3V	according to th table. Let sit fo or 48±4 hour (temperature, th	e four heat trea r 24±2 hours (1 high dielectric o hen measure.	atments li temperationstant	sted in the folloure compensatives at room	owing iting type)
	Tomporaturo			0.05max. (C<3.3µF)	Step	1	2	3	4
15	Cycle	Q/D.F.	30pFmin. : Q≧1000 30pFmax. : Q≧400+20C C : Nominal Capacitance (pE)	0.1max. (C≥3.3µF) [E4] W.V. : 25Vmin. : 0.025max.	Temp. (℃)	Min. Operating Temp.+0/-3	Room Temp.	Max. Operating Temp.+3/-0	Room Temp.
			C. Norminal Capacitance (pr)	[F5]	Time (min.)	30±3	2 to 3	30±3	2 to 3
				 W.V.: 25Vmin. : 0.05max. (C<0.10μF) : 0.09max. (C≥0.10μF) W.V.: 16V/10V : 0.125max. W.V.: 6.3Vmax.: 0.15max. 	•Initial measurement for high dielectric constant type Perform a heat treatment at $150 \pm 18^{\circ}$ for one hour and then let sit for 48±4 hours at room temperature. Perform the initial measurement.				and then
		I.R.	More than 10,000M Ω or 500 Ω •	F (Whichever is smaller)					
		Dielectric Strength	No failure						



Continued from the preceding page.

			Specifi	cations	
No.	Ite	m	Temperature Compensating Type	High Dielectric Type	Test Method
			The measured and observed ch specifications in the following ta	aracteristics should satisfy the ble.	
		Appearance	No marking defects		
		Capacitance Change	Within $\pm 5\%$ or ± 0.5 pF (Whichever is larger)	R6, R7 : Within ±12.5% E4, F5 : Within ±30%	
16	Humidity Steady State	Q/D.F.	30pF and over : Q≥350 10pF and over 30pF and below : Q≥275+5C/2 10pF and below : Q≥200+10C C : Nominal Capacitance (pF)	[R6, R7] W.V. : 25Vmin. : 0.05max. W.V. : 16/10V : 0.05max. W.V. : 6.3V 0.075max. (C<3.3µF) 0.125max. (C≥3.3µF) [E4] W.V. : 25Vmin. : 0.05max. [F5] W.V. : 25Vmin. : 0.075max. (C<0.10µF) : 0.125max. (C≥0.10µF) W.V. : 16V/10V : 0.15max. W.V. : 6.3Vmax. : 0.2max.	Let the capacitor sit at 40±2°C and 90 to 95% humidity for 500±12 hours. Remove and let sit for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type) at room tem- perature, then measure.
		I.R.	More than 1,000M Ω or 50 Ω • F	(Whichever is smaller)	•
		Dielectric Strength	No failure		
			The measured and observed ch specifications in the following ta	aracteristics should satisfy the ble.	
		Appearance	No marking defects		
		Capacitance Change	Within ±7.5% or ±0.75pF (Whichever is larger)	R6, R7 : Within ±12.5% E4 : Within ±30% F5 : Within ±30% [W.V. : 10Vmax.] F5 : Within +30/-40%	
17	Humidity Load	Q/D.F.	30pF and over : Q≥200 30pF and below : Q≥100+10C/3 C : Nominal Capacitance (pF)	$[R6, R7] \\ W.V. : 25Vmin. : 0.05max. \\ W.V. : 16/10V : 0.05max. \\ W.V. : 6.3V \\ 0.075max. (C<3.3\muF) \\ 0.125max. (C\geq3.3\muF) \\ [E4] \\ W.V. : 25Vmin. : 0.05max. \\ [F5] \\ W.V. : 25Vmin. \\ : 0.075max. (C<0.10\muF) \\ : 0.125max. (C\geq0.10\muF) \\ W.V. : 16V/10V : 0.15max. \\ W.V. : 6.3Vmax. : 0.2max. \\ W.V. : 0.2max \\ W.V. : 0.2max \\ W.V. : 0.2max \\ W.V. : $	 Apply the rated voltage at 40±2°C and 90 to 95% humidity for 500±12 hours. Remove and let sit for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type) at room temperature, then measure. The charge/discharge current is less than 50mA. Initial measurement for F5/10V max. Apply the rated DC voltage for 1 hour at 40±2°C. Remove and let sit for 48±4 hours at room temperature. Perform initial measurement.
		I.R.	More than 500MΩ or 25Ω • F (V	Vhichever is smaller)	
		Dielectric Strength	No failure		



Continued from the preceding page.

			Specifi	cations	
No.	lte	em	Temperature Compensating Type	High Dielectric Type	Test Method
			The measured and observed ch specifications in the following ta	naracteristics should satisfy the ble.	
		Appearance	No marking defects		
		Capacitance Change	Within ±3% or ±0.3pF (Whichever is larger)	R6, R7 : Within ±12.5% E4 : Within ±30% F5 : Within ±30% (Cap<1.0μF) F5 : Within +30/−40% (Cap≧1.0μF)	Apply 200% of the rated voltage for 1000±12 hours at the
18	High Temperature Load	Q/D.F.	30pF and over : Q≥350 10pF and over 30pF and below : Q≥275+5C/2 10pF and below : Q≥200+10C C : Nominal Capacitance (pF)	$ \begin{array}{l} [{\sf R6}, {\sf R7}] \\ {\sf W.V.} : 25{\sf Vmin.} : 0.05{\sf max.} \\ {\sf W.V.} : 16/10{\sf V} : 0.05{\sf max.} \\ {\sf W.V.} : 6.3{\sf V} \\ 0.075{\sf max.} ({\sf C}{<}3.3\mu{\sf F}) \\ 0.125{\sf max.} ({\sf C}{\geq}3.3\mu{\sf F}) \\ [{\sf E4}] \\ {\sf W.V.} : 25{\sf Vmin.} : 0.05{\sf max} \\ [{\sf F5}] \\ {\sf W.V.} : 25{\sf Vmin.} \\ : 0.075{\sf max.} ({\sf C}{<}0.10\mu{\sf F}) \\ : 0.125{\sf max.} ({\sf C}{\geq}0.10\mu{\sf F}) \\ : 0.125{\sf max.} ({\sf C}{\geq}0.10\mu{\sf F}) \\ {\sf W.V.} : 16{\sf V}/10{\sf V} : 0.15{\sf max.} \\ \\ {\sf W.V.} : 6.3{\sf Vmax.} : 0.2{\sf max.} \\ \end{array} $	maximum operating temperature ±3°C. Let sit for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type) at room temperature, then measure. The charge/discharge current is less than 50mA. •Initial measurement for high dielectric constant type. Apply 200% of the rated DC voltage for one hour at the maximum operating temperature ±3°C. Remove and let sit for 48±4 hours at room temperature. Perform initial measurement. *150% for 500V and C≥10µF
		I.R.	More than 1,000M Ω or 50 Ω •F (, Whichever is smaller)	
		Dielectric Strength	No failure		

Table A

		Capacitance Change from 25°C (%)						
Char. Code	Nominal Values (ppm/℃)*	_!	55	-30		-10		
		Max.	Min.	Max.	Min.	Max.	Min.	
5C	0 ± 30	0.58	-0.24	0.40	-0.17	0.25	-0.11	
6C	0 ± 60	0.87	-0.48	0.59	-0.33	0.38	-0.21	
6P	-150 ± 60	2.33	0.72	1.61	0.50	1.02	0.32	
6R	-220 ± 60	3.02	1.28	2.08	0.88	1.32	0.56	
6S	-330 ± 60	4.09	2.16	2.81	1.49	1.79	0.95	
6T	-470 ± 60	5.46	3.28	3.75	2.26	2.39	1.44	
7U	-750 ±120	8.78	5.04	6.04	3.47	3.84	2.21	
1X	+350 to -1000	-	_	-	-	-	-	

*Nominal values denote the temperature coefficient within a range of 25℃ to 125℃ (for △C)/85℃ (for other TC).



Continued from the preceding page.

Part Number				GR	M15							
L x W [EIA]				1.00x0.	50 [0402]							
тс	C0G (5C)	P2H (6P)	R2H (6R)	S2H (6S)	(1	SL X)	T2H (6T)	U2J (7U)				
Rated Volt.	50 (1H)	50 (1H)	50 (1H)	50 (1H)	50 (1H)	25 (1E)	50 (1H)	50 (1H)				
Capacitance (Ca	Capacitance (Capacitance part numbering code) and T (mm) Dimension (T Dimension part numbering code)											
39pF(390)	0.50 (5)			0.50 (5)			0.50(5)	0.50 (5)				
47pF(470)	0.50 (5)				0.50(5)		0.50(5)	0.50(5)				
56pF(560)	0.50 (5)				0.50(5)		0.50(5)	0.50(5)				
68pF(680)	0.50 (5)				0.50(5)		0.50(5)	0.50(5)				
82pF(820)	0.50 (5)				0.50(5)		0.50(5)	0.50(5)				
100pF(101)	0.50 (5)				0.50(5)		0.50(5)	0.50(5)				
120pF(121)	0.50 (5)				0.50(5)			0.50(5)				
150pF(151)	0.50 (5)				0.50(5)			0.50(5)				
180pF(181)	0.50 (5)				0.50(5)			0.50(5)				
220pF(221)	0.50 (5)					0.50(5)						
270pF(271)	0.50 (5)					0.50(5)						
330pF(331)	0.50 (5)					0.50(5)						
390pF(391)	0.50 (5)					0.50(5)						
470pF(471)	0.50 (5)											
560pF(561)	0.50 (5)											
680pF(681)	0.50 (5)											
820pF(821)	0.50 (5)											
1000pF(102)	0.50 (5)											

The part numbering code is shown in ().

Dimensions are shown in mm and Rated Voltage in Vdc.

Temperature Compensating Type GRM18 Series (1.60x0.80 mm) 200V/100V/50V/25V

Part Number						GR	M18					
L x W [EIA]						1.60x0.8	30 [0603]					
тс		C0G (5C)		P2H (6P)	R2H (6R)	S2H (6S)		S (1	L X)		T2H (6T)	U2J (7U)
Rated Volt.	200 (2D)	100 (2A)	50 (1H)	50 (1H)	50 (1H)	50 (1H)	200 (2D)	100 (2A)	50 (1 H)	25 (1E)	50 (1H)	50 (1H)
Capacitance (Ca	pacitance	part numbe	ering code)	and T (mm) Dimensio	n (T Dimen	sion part n	umbering o	ode)			1
0.50pF(R50)	0.80(8)	0.80(8)	0.80(8)									
0.75pF(R75)	0.80(8)	0.80(8)	0.80(8)									
1.0pF(1R0)	0.80(8)	0.80(8)	0.80(8)									
2.0pF(2R0)	0.80(8)	0.80(8)	0.80(8)									
3.0pF(3R0)	0.80(8)	0.80(8)	0.80(8)	0.80(8)	0.80(8)	0.80(8)					0.80(8)	0.80(8)
4.0pF(4R0)	0.80(8)	0.80(8)	0.80(8)	0.80(8)	0.80(8)	0.80(8)					0.80(8)	0.80(8)
5.0pF(5R0)	0.80(8)	0.80(8)	0.80(8)	0.80(8)	0.80(8)	0.80(8)					0.80(8)	0.80(8)
6.0pF(6R0)	0.80(8)	0.80(8)	0.80(8)	0.80(8)	0.80(8)	0.80(8)					0.80(8)	0.80(8)
7.0pF(7R0)	0.80(8)	0.80(8)	0.80(8)	0.80(8)	0.80(8)	0.80(8)					0.80(8)	0.80(8)
8.0pF(8R0)	0.80(8)	0.80(8)	0.80(8)	0.80(8)	0.80(8)	0.80(8)					0.80(8)	0.80(8)
9.0pF(9R0)	0.80(8)	0.80(8)	0.80(8)	0.80(8)	0.80(8)	0.80(8)					0.80(8)	0.80(8)
10pF(100)	0.80(8)	0.80(8)	0.80(8)	0.80(8)	0.80(8)	0.80(8)					0.80(8)	0.80(8)
12pF(120)		0.80(8)	0.80(8)	0.80(8)	0.80(8)	0.80(8)	0.80(8)				0.80(8)	0.80(8)
15pF(150)		0.80(8)	0.80(8)	0.80(8)	0.80(8)	0.80(8)	0.80(8)				0.80(8)	0.80(8)
18pF(180)		0.80(8)	0.80(8)	0.80(8)	0.80(8)	0.80(8)	0.80(8)				0.80(8)	0.80(8)
22pF(220)		0.80(8)	0.80(8)	0.80(8)	0.80(8)	0.80(8)	0.80(8)				0.80(8)	0.80(8)
27pF(270)		0.80(8)	0.80(8)	0.80(8)	0.80(8)	0.80(8)	0.80(8)				0.80(8)	0.80(8)
33pF(330)		0.80(8)	0.80(8)	0.80(8)	0.80(8)	0.80(8)	0.80(8)				0.80(8)	0.80(8)
39pF(390)		0.80(8)	0.80(8)	0.80(8)	0.80(8)	0.80(8)	0.80(8)				0.80(8)	0.80(8)
47pF(470)		0.80(8)	0.80(8)	0.80(8)	0.80(8)	0.80(8)	0.80(8)				0.80(8)	0.80(8)
56pF(560)		0.80(8)	0.80(8)	0.80(8)	0.80(8)	0.80(8)	0.80(8)				0.80(8)	0.80(8)

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Part Number						GR	M18					
L x W [EIA]						1.60x0.8	80 [0603]					
тс		C0G (5C)		P2H (6P)	R2H (6R)	S2H (6S)		S (1	SL X)		T2H (6T)	U2J (7U)
Rated Volt.	200 (2D)	100 (2A)	50 (1H)	50 (1H)	50 (1H)	50 (1H)	200 (2D)	100 (2A)	50 (1H)	25 (1E)	50 (1H)	50 (1H)
Capacitance (Ca	pacitance	part numbe	ering code)	and T (mm) Dimensio	n (T Dimen	sion part n	umbering c	ode)			
68pF(680)		0.80(8)	0.80(8)	0.80(8)	0.80(8)	0.80(8)	0.80(8)		0.80(8)		0.80(8)	0.80(8)
82pF(820)		0.80(8)	0.80(8)	0.80(8)	0.80(8)	0.80(8)	0.80(8)		0.80(8)		0.80(8)	0.80(8)
100pF(101)		0.80(8)	0.80(8)	0.80(8)	0.80(8)	0.80(8)	0.80(8)		0.80(8)		0.80(8)	0.80(8)
120pF(121)		0.80(8)	0.80(8)	0.80(8)	0.80(8)	0.80(8)		0.80(8)	0.80(8)		0.80(8)	0.80(8)
150pF(151)		0.80(8)	0.80(8)	0.80(8)	0.80(8)	0.80(8)		0.80(8)	0.80(8)		0.80(8)	0.80(8)
180pF(181)		0.80(8)	0.80(8)		0.80(8)	0.80(8)		0.80(8)	0.80(8)		0.80(8)	0.80(8)
220pF(221)		0.80(8)	0.80(8)			0.80(8)		0.80(8)	0.80(8)		0.80(8)	0.80(8)
270pF(271)		0.80(8)	0.80(8)					0.80(8)	0.80(8)		0.80(8)	0.80(8)
330pF(331)		0.80(8)	0.80(8)					0.80(8)	0.80(8)		0.80(8)	0.80(8)
390pF(391)		0.80(8)	0.80(8)					0.80(8)	0.80(8)		0.80(8)	0.80(8)
470pF(471)		0.80(8)	0.80(8)						0.80(8)			0.80(8)
560pF(561)		0.80(8)	0.80(8)						0.80(8)			0.80(8)
680pF(681)			0.80(8)						0.80(8)			0.80(8)
820pF(821)			0.80(8)							0.80(8)		
1000pF(102)			0.80(8)							0.80(8)		
1200pF(122)			0.80(8)							0.80(8)		
1500pF(152)			0.80(8)							0.80(8)		
1800pF(182)			0.80(8)									
2200pF(222)			0.80(8)									
2700pF(272)			0.80(8)									

The part numbering code is shown in ().

Dimensions are shown in mm and Rated Voltage in Vdc.

Temperature Compensating Type GRM21 Series (2.00x1.25 mm) 200V/100V/50V/25V

Part Number							GRM21						
L x W [EIA]						2.0	0x1.25 [08	305]					
тс		C0G (5C)		C0H (6C)	P2H (6P)	R2H (6R)	S2H (6S)		(1	SL X)		T2H (6T)	U2J (7U)
Rated Volt.	200 (2D)	100 (2A)	50 (1H)	25 (1E)	50 (1H)	50 (1H)	50 (1H)	200 (2D)	100 (2A)	50 (1H)	25 (1E)	50 (1H)	50 (1H)
Capacitance (Ca	pacitance	e part num	bering coo	de) and T (mm) Dime	ension (T D	imension	part numb	ering code	e)			
12pF(120)	0.85(9)												
15pF(150)	0.85(9)												
18pF(180)	0.85(9)												
22pF(220)	0.85(9)												
27pF(270)	0.85(9)												
33pF(330)	0.85(9)												
39pF(390)	0.85(9)												
47pF(470)	0.85(9)												
56pF(560)	0.85(9)												
68pF(680)	1.25(B)	0.85(9)											
82pF(820)	1.25(B)	0.85(9)											
100pF(101)	1.25(B)	0.60(6)											
120pF(121)	1.25(B)	0.60(6)						0.85(9)					
150pF(151)	1.25(B)	0.60(6)						1.25(B)					
180pF(181)	1.25(B)	0.60(6)			0.85(9)			1.25(B)					
220pF(221)	1.25(B)	0.60(6)			0.85(9)	0.85(9)		1.25(B)					
270pF(271)		0.60(6)			0.85(9)	0.85(9)	0.85(9)	1.25(B)					
330pF(331)		0.60(6)			0.85(9)	0.85(9)	0.85(9)	1.25(B)					
390pF(391)		0.60(6)			1.25(B)	0.85(9)	0.85(9)	1.25(B)					



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Part Number							GRM21	0					
L x W [EIA]						2.0	0x1.25 [08	305]					
тс		C0G (5C)		C0H (6C)	P2H (6P)	R2H (6R)	S2H (6S)		S (1	L X)		T2H (6T)	U2J (7U)
Rated Volt.	200 (2D)	100 (2A)	50 (1H)	25 (1E)	50 (1H)	50 (1H)	50 (1H)	200 (2D)	100 (2A)	50 (1H)	25 (1E)	50 (1H)	50 (1H)
Capacitance (Ca	pacitance	e part num	bering coo	de) and T (mm) Dime	nsion (T D	imension	part numb	ering code	e)			
470pF(471)		0.60(6)			1.25(B)	0.85(9)	0.85(9)	1.25(B)	0.85(9)				
560pF(561)		0.60(6)			1.25(B)	1.25(B)	1.25(B)		0.85(9)			1.25(B)	
680pF(681)		0.85(9)				1.25(B)	1.25(B)		0.85(9)			1.25(B)	
820pF(821)		0.85(9)					1.25(B)		1.25(B)	0.60(6)		1.25(B)	0.60 (6)
1000pF(102)		0.85(9)							1.25(B)	0.60(6)		1.25(B)	0.60(6)
1200pF(122)									1.25(B)	0.60(6)		1.25(B)	0.60(6)
1500pF(152)									1.25(B)	0.85(9)		1.25(B)	0.85(9)
1800pF(182)			0.60(6)						1.25(B)	0.85(9)		1.25(B)	0.85(9)
2200pF(222)			0.60(6)							0.85(9)			0.85(9)
2700pF(272)			0.60(6)	1.25(B)						1.25(B)			1.25(B)
3300pF(332)			0.60(6)	1.25(B)						1.25(B)			1.25(B)
3900pF(392)			0.60(6)	1.25(B)							0.85(9)		
4700pF(472)			0.60(6)								0.85(9)		
5600pF(562)			0.85(9)								1.25(B)		
6800pF(682)			0.85(9)								1.25(B)		
8200pF(822)			0.85(9)										
10000pF(103)			0.85(9)							0.60(6)			0.60(6)
12000pF(123)										0.60(6)			0.60(6)
15000pF(153)										0.60(6)			0.60(6)
18000pF(183)										0.60(6)			0.60(6)
22000pF(223)										0.85(9)			0.85(9)
27000pF(273)										0.85(9)			0.85(9)
33000pF(333)										1.00(A)			1.00(A)
39000pF(393)										1.25(B)			1.25(B)
47000pF(473)										1.25(B)			1.25(B)

The part numbering code is shown in ().

Dimensions are shown in mm and Rated Voltage in Vdc.

Temperature Compensating Type GRM31 Series (3.20x1.60 mm) 500V/200V/100V/50V/25V

Part Number							GR	M31						
L x W [EIA]							3.20x1.6	50 [1206]						
тс		C((5	0G (C)		C0H (6C)	P2H (6P)	R2H (6R)	S2H (6S)		(1	SL X)		T2H (6T)	U2J (7U)
Rated Volt.	500 (2H)	200 (2D)	50 (1H)	25 (1E)	25 (1E)	50 (1H)	50 (1H)	50 (1H)	200 (2D)	100 (2A)	50 (1H)	25 (1E)	50 (1H)	50 (1H)
Capacitance (Ca	apacitance	e part nur	mbering c	ode) and	T (mm) D	imension	(T Dimen	sion part	numberir	ng code)				
1.0pF(1R0)	1.15(M)													
2.0pF(2R0)	1.15(M)													
3.0pF(3R0)	1.15(M)													
4.0pF(4R0)	1.15(M)													
5.0pF(5R0)	1.15(M)													
6.0pF(6R0)	1.15(M)													
7.0pF(7R0)	1.15(M)													
8.0pF(8R0)	1.15(M)													
9.0pF(9R0)	1.15(M)													
10pF(100)	1.15(M)													
12pF(120)	1.15(M)													
15pF(150)	1.15(M)													
18pF(180)	1.15(M)													
22pF(220)	1.15(M)													



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Part Number							GR	M31	1					
L x W [EIA]							3.20x1.6	0 [1206]						
тс		C((5)G C)		C0H (6C)	P2H (6P)	R2H (6R)	S2H (6S)		S (1	L X)		T2H (6T)	U2J (7U)
Rated Volt.	500 (2H)	200 (2D)	50 (1H)	25 (1E)	25 (1E)	50 (1H)	50 (1H)	50 (1H)	200 (2D)	100 (2A)	50 (1H)	25 (1E)	50 (1H)	50 (1 H)
Capacitance (Ca	pacitance	e part nur	nbering c	ode) and	T (mm) D	imension	(T Dimen	sion part	numberin	ig code)				
27pF(270)	1.15(M)													
33pF(330)	1.15(M)													
39pF(390)	1.15(M)													
47pF(470)	1.15(M)													
56pF(560)	1.15(M)													
68pF(680)	1.15(M)													
82pF(820)	1.15(M)													
270pF(271)		1.15(M)												
330pF(331)		1.15(M)												
390pF(391)		1.15(M)												
470pF(471)		1.15(M)												
560pF(561)									1.15(M)					
680pF(681)						0.85(9)			1.15(M)					
820pF(821)						0.85(9)	0.85(9)		1.15(M)					
1000pF(102)						1.15(M)	1.15(M)	0.85(9)	1.15(M)					
1200pF(122)						1.15(M)	1.15(M)	1.15(M)	1.15(M)					
1500pF(152)						1.15(M)	1.15(M)	1.15(M)						
1800pF(182)								1.15(M)						
2200pF(222)										1.15(M)			1.15(M)	
2700pF(272)										1.15(M)			1.15(M)	
3300pF(332)										1.15(M)			1.15(M)	
3900pF(392)										1.15(M)	0.85(9)		1.15(M)	0.85(9)
4700pF(472)										1.15(M)	0.85(9)			0.85(9)
5600pF(562)			0.85(9)								0.85(9)			0.85(9)
6800pF(682)			0.85(9)		0.85(9)						1.15(M)			1.15(M)
8200pF(822)			0.85(9)		1.15(M)						1.15(M)			1.15(M)
10000pF(103)			0.85(9)									1.15(M)		
12000pF(123)												1.15(M)		
15000pF(153)												1.15(M)		
27000pF(273)			0.85(9)											
33000pF(333)			0.85(9)											
47000pF(473)			1.15(M)											
56000pF(563)											0.85(9)			0.85(9)
68000pF(683)											1.15(M)			1.15(M)
82000pF(823)											1.15(M)			1.15(M)
0.10μF(104)				1.60(C)							1.15(M)			1.15(M)

The part numbering code is shown in $% \left({\left. {{{\bf{n}}_{\rm{s}}}} \right)_{\rm{s}}} \right)$ ().

Dimensions are shown in mm and Rated Voltage in Vdc.

High Dielectric Constant Type X5R (R6) Characteristics

тс				X! (R	5R (6)			
Part Number	GRI	M15	GRI	V18	GR	M21	GRI	V I31
L x W [EIA]	1.00x0.5	50 [0402]	1.60x0.8	0 [0603]	2.00x1.2	25 [0805]	3.20x1.6	0 [1206]
Rated Volt.	16 (1C)	10 (1A)	10 (1A)	6.3 (0J)	10 (1A)	6.3 (0J)	10 (1A)	6.3 (0J)
Capacitance (Ca	pacitance part r	numbering code)	and T (mm) Dim	ension (T Dimen	sion part numbe	ring code)		
68000pF(683)		0.50 (5)						
0.10μF(104)	0.50 (5)	0.50 (5)						
0.33µF(334)			0.80(8)					



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тс				X! (F	5R 8 6)			
Part Number	GRI	M15	GR	M18	GR	M21	GR	V I31
L x W [EIA]	1.00x0.5	50 [0402]	1.60x0.8	30 [0603]	2.00x1.	25 [0805]	3.20x1.6	0 [1206]
Rated Volt.	16 (1C)	10 (1A)	10 (1A)	6.3 (0J)	10 (1A)	6.3 (0J)	10 (1A)	6.3 (0J)
Capacitance (Ca	pacitance part r	numbering code)	and T (mm) Dim	ension (T Dimen	sion part numbe	ering code)		
0.47µF(474)			0.80(8)					
0.68μF(684)			0.80(8)					
1.0μF(105)			0.80(8)	0.80 (8)	0.85(9)			
1.5μF(155)						0.85(9)		
2.2μF(225)					1.25(B)	1.25(B)	0.85(9)	
3.3μF(335)						1.25(B)	1.30(X)	
4.7μF(475)						1.25(B)	1.60(C)	1.15(M)
10μF(106)							1.60(C)	1.60(C)

The part numbering code is shown in each ().

 $3.3\mu F$ and $4.7\mu F,\, 6.3V$ rated are GRM21 series of L: 2±0.15, W: 1.25±0.15, T: 1.25±0.15.

T: 1.15 \pm 0.1mm is also available for GRM31 1.0µF for 16V.

Dimensions are shown in mm and Rated Voltage in Vdc.

High Dielectric Constant Type X7R (R7) Characteristics

тс									X. (R	7R 2 7)								
Part Number		GRI	M15				GRM18	;			GR	M21				GRM31		
L x W [EIA]	1	.00x0.5	50 [040]	2]		1.60	x0.80 [(0603]		2	.00x1.2	25 [080	5]		3.20	x1.60 [′	1206]	
Rated Volt.	50 (1H)	25 (1E)	16 (1C)	10 (1A)	100 (2A)	50 (1H)	25 (1E)	16 (1C)	10 (1A)	100 (2A)	50 (1H)	25 (1E)	16 (1C)	100 (2A)	50 (1H)	25 (1E)	16 (1C)	10 (1A)
Capacitance (Ca	pacitar	nce part	t numbe	ering co	de) and	d T (mm) Dimer	nsion (T	Dimen	sion pa	rt num	pering c	ode)					
220pF (221)	0.50 (5)					0.80 (8)												
330pF (331)	0.50 (5)					0.80 (8)												
470pF (471)	0.50 (5)					0.80 (8)												
680pF (681)	0.50 (5)					0.80 (8)												
1000pF (102)	0.50 (5)					0.80 (8)												
1500pF (152)	0.50 (5)					0.80 (8)												
2200pF (222)	0.50 (5)				0.80 (8)	0.80 (8)												
3300pF (332)	0.50 (5)				0.80 (8)	0.80 (8)												
4700pF (472)	0.50 (5)					0.80 (8)				0.85 (9)								
6800pF (682)		0.50 (5)				0.80 (8)				0.85 (9)								
10000pF (103)		0.50 (5)				0.80 (8)				1.25 (B)								
15000pF (153)			0.50 (5)			0.80 (8)												
22000pF (223)			0.50 (5)			0.80 (8)												
33000pF (333)				0.50 (5)		0.80 (8)	0.80 (8)				0.85 (9)			1.15 (M)				



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тс									X. (R	7R 2 7)								
Part Number		GR	M15	-			GRM18				GR	M21				GRM31		
L x W [EIA]	1	.00x0.5	50 [040	2]		1.60	x0.80 [(0603]		2	.00x1.2	25 [080	5]		3.20	x1.60 [1	206]	
Rated Volt.	50 (1H)	25 (1E)	16 (1C)	10 (1A)	100 (2A)	50 (1H)	25 (1E)	16 (1C)	10 (1A)	100 (2A)	50 (1H)	25 (1E)	16 (1C)	100 (2A)	50 (1H)	25 (1E)	16 (1C)	10 (1A)
Capacitance (Ca	pacitar	nce par	t numbe	ering co	de) and	d T (mm) Dimer	nsion (T	Dimen	sion pa	rt numb	pering c	ode)					
47000pF (473)				0.50 (5)		0.80 (8)	0.80 (8)				1.25 (B)			1.15 (M)				
68000pF (683)						0.80 (8)	0.80 (8)				1.25 (B)							
0.10μF (104)			0.50 (5)	0.50 (5)		0.80 (8)	0.80 (8)	0.80 (8)			1.25 (B)	1.25 (B)						
0.15μF (154)							0.80 (8)		0.80 (8)		1.25 (B)	1.25 (B)						
0.22μF (224)								0.80 (8)	0.80 (8)		1.25 (B)	0.85 (9)						
0.33μF (334)											0.85 (9)	1.25 (B)			0.85 (9)			
0.47μF (474)											1.25 (B)	1.25 (B)	0.85 (9)		1.15 (M)			
0.68μF (684)													0.85 (9)			0.85 (9)		
1.0μF (105)													1.25 (B)		1.15 (M)	1.15 (M)	0.85 (9)	0.85 (9)
1.5μF (155)															1.60 (C)		1.15 (M)	
2.2μF (225)															1.60 (C)		1.15 (M)	0.85 (9)
3.3μF (335)																1.60 (C)		
4.7μF (475)																1.60 (C)		

The part numbering code is shown in each ().

The tolerance will be changed to L: 3.2 \pm 0.2, W: 1.6 \pm 0.2 for GRM31 16V 1.0 μ F type. Also L: 3.2 \pm 0.2, W: 1.6 \pm 0.2, T: 1.15 \pm 0.15 for GRM31 16V 1.5 μ F and 2.2 μ F type. Dimensions are shown in mm and Rated Voltage in Vdc.

High Dielectric Constant Type Y5V (F5) Characteristics

тс				1					Y5V (F5)								
Part Number		GRM15				GRM18				GR	M21				GRM31		
L x W [EIA]	1.00	x0.50 [0	0402]		1.60	x0.80 [0	0603]		2	2.00x1.2	25 [0805	5]		3.20	x1.60 [1	206]	
Rated Volt.	50 (1H)	25 (1E)	16 (1C)	100 (2A)	50 (1H)	25 (1E)	16 (1C)	10 (1A)	50 (1H)	25 (1E)	16 (1C)	10 (1A)	50 (1H)	25 (1E)	16 (1C)	10 (1A)	6.3 (0J)
Capacitance (Ca	pacitan	ce part	number	ing cod	e) and T	- (mm) [Dimensi	on (T Dii	nensior	part nu	umberin	g code)					
2200pF (222)	0.50 (5)																
4700pF (472)	0.50 (5)			0.80 (8)													
10000pF (103)	0.50 (5)				0.80 (8)												
22000pF (223)		0.50 (5)			0.80 (8)												
47000pF (473)			0.50 (5)		0.80 (8)												
0.10μF (104)		0.50 (5)	0.50 (5)		0.80 (8)	0.80 (8)			0.85 (9)								



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тс									Y5V (F5)								
Part Number		GRM15				GRM18				GRI	M21				GRM31		
L x W [EIA]	1.00	x0.50 [C	0402]		1.60	x0.80 [C	0603]		2	2.00x1.2	5 [0805	5]		3.20	x1.60 [1	206]	
Rated Volt.	50 (1H)	25 (1E)	16 (1C)	100 (2A)	50 (1H)	25 (1E)	16 (1C)	10 (1A)	50 (1 H)	25 (1E)	16 (1C)	10 (1A)	50 (1 H)	25 (1E)	16 (1C)	10 (1A)	6.3 (0J)
Capacitance (Ca	pacitan	ce part	number	ing cod	e) and T	" (mm) E	Dimensio	on (T Dir	mensior	part nu	Imberin	g code)					
0.22μF (224)							0.80 (8)		1.25 (B)	0.85 (9)							
0.47μF (474)							0.80 (8)	0.80 (8)		1.25 (B)			1.15 (M)				
1.0μF (105)							0.80 (8)	0.80 (8)		0.85 (9)	0.85 (9)	0.85 (9)		1.15 (M)	0.85 (9)		
2.2μF (225)										1.25 (B)	1.25 (B)	1.25 (B)			1.15 (M)	0.85 (9)	
4.7μF (475)												1.25 (B)		1.15 (M)	1.15 (M)	1.15 (M)	
10μF (106)														1.60 (C)		1.15 (M)	1.15 (M)

The part numbering code is shown in each ().

T: 1.25 $\pm 0.1 mm$ is also available for GRM21 25V or 16V 1.0 μF type.

Dimensions are shown in mm and Rated Voltage in Vdc.

High Dielectric Constant Type Z5U (E4) Characteristics

тс	Z5U (E4)						
Part Number	GRM18	GRM21	GRM31				
L x W [EIA]	1.60x0.80 [0603]	2.00x1.25 [0805]	3.20x1.60 [1206]				
Rated Volt.	50 (1H)	50 (1H)	50 (1H)				
Capacitance (Ca	pacitance part numbering code) and T (mm) Dimension (T Dimension part numbering c	ode)				
10000pF(103)	0.80(8)						
22000pF(223)	0.80(8)						
47000pF(473)		0.60 (6)					
0.10μF(104)		0.85 (9)					
0.22µF(224)			0.85 (9)				

The part numbering code is shown in ().

Dimensions are shown in mm and Rated Voltage in Vdc.



			Specifications				
No.	lte	em	Temperature Compensating Type	High Dielectric Type	-	Test Method	
1	Operating Temperature -55 to +125°C R6 : -55 to +85°C R7 : -55 to +125°C R7 : -55 to +125°C E4 : +10 to +85°C F5 : -30 to +85°C						
2	2 Rated Voltage		See the previous page.		The rated voltage is defined as the maximum voltage which may be applied continuously to the capacitor. When AC voltage is superimposed on DC voltage, V ^{P,P} or V ^{O,P} , whichever is larger, should be maintained within the rated voltage range.		
3	Appearar	ice	No defects or abnormalities		Visual inspection		
4	Dimensio	ns	Within the specified dimensions		Using calipers on m	crometer	
5	5 Dielectric Strength		No defects or abnormalities		No failure should be observed when *300% of the rated voltage (C0 Δ to U2J and SL) or *250% of the rated voltage (X5R, X7R, Z5U and Y5V) is applied between the terminations for 1 to 5 seconds, provided the charge/discharge current is less than 50mA. *200% for 500V		
6	Insulatior Resistanc	i ce	More than 10,000M Ω or 500 Ω • F (Whichever is smaller)		The insulation resistance should be measured with a DC voltage not exceeding the rated voltage at 25°C and 75%RH max. and within 2 minutes of charging.		
7	Capacita	nce	Within the specified tolerance		The capacitance/Q/I frequency and voltage	D.F. should be measu ge shown in the table.	red at 25℃ at the
				[R6, R7]	Item Cha	ar. Frequency	Voltage
			 W.V.: 25Vmin.: 0.025max. W.V.: 16/10V : 0.035max. W.V.: 6.3V 0.05max.(C<3.3µF) 0.1max.(C≥3.3µF) [E4] W.V.: 25Vmin.: 0.025max. [F5] W.V.: 25Vmin. : 0.05max.(C<0.10µF) : 0.09max.(C≥0.10µF) W.V.: 16V/10V : 0.125max. 	ΔC to 7U, 1X (1000pF and below)	1±0.1MHz	0.5 to 5Vrms	
8	Q/ Dissipation Factor (D.F.)			actor 30pFmin. : Q≧1000 30pFmax. : Q≧400+20C C : Nominal Capacitance (pF)	ΔC to 7U, 1X (more than 1000pF)	1±0.1kHz	1±0.2Vrms
					R6, R7, F5 (10µF and below) 1±0.1kHz	1±0.2Vrms
					R6, R7, F5 (more than 10μF) 120±24Hz	0.5±0.1Vrms
				W.V. : 6.3Vmax. : 0.15max.	E4	1±0.1kHz	0.5±0.05Vrms
		Capacitance Within the : Change (Table A)	Within the specified tolerance (Table A)	R6 : Within $\pm 15\%$ (-55 to +85°C) R7 : Within $\pm 15\%$ (-55 to +125°C) E4 : Within +22/-56% (+10 to +85°C) F5 : Within +22/-82% (-30 to +85°C)	The capacitance cha each specified temp (1) Temperature Co The temperature co Capacitance measu When cycling the tei $5 (C0\Delta : +25^{\circ}C to +$ $+85^{\circ}C)$ the capacitan for the temperature	ured after 5 min. at using the prence. y from step 1 through effs. : +25°c to he specified tolerance tance change as	
	Capacitance	Tomporatura	emperature Within the specified tolerance (Table A)		Table A. The capacitance drii between the maximu 1, 3 and 5 by the ca	t is calculated by dividum and minimum mea	ding the differences isured values in steps p 3.
9	Characteristics	Coefficient			Step 1	lemperat 25+	ture(°C)
					2	-55±3 (for ∆C to -30±3 (f 10±3 (fo	7U/1X/R6/R7) for F5) or E4)
					3	25±	2
		APR -	Within +0.2% or +0.05pF		4	4 125±3 (for △C/R7) 85±3 (for other TC)	
		Capacitance	(Whichever is larger.)		5	25±	2
		טווונ	*Does not apply to 1X/25V		(2) High Dielectric C The ranges of capac 25℃ value over the should be within the	onstant Type sitance change compa temperature ranges sl specified ranges.	ared with the above hown in the table



Continued from the preceding page.

			Specifi	cations				
No.	lte	m	Temperature Compensating Type	High Dielectric Type	Test Method			
10	10 Adhesive Strength of Termination		No removal of the terminations or other defect should occur.		Solder the capacitor to the test jig (glass epoxy board) shown in Fig. 1 using a eutectic solder. Then apply 10N* force in parallel with the test jig for 10±1sec. The soldering should be done either with an iron or using the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock. *2N (GR□03) 5N (GR□15, GRM18)			
	Appearance		No defects or abnormalities					
11		Capacitance	Within the specified tolerance					
	Vibration Resistance	Q/D.F.	30pFmin. : Q≧1000 30pFmax. : Q≧400+20C C : Nominal Capacitance (pF)	$\begin{array}{l} [R6,R7] \\ W.V.: 25Vmin.: 0.025max. \\ W.V.: 16/10V: 0.035max. \\ W.V.: 6.3V: \\ 0.05max. (C{<}3.3\muF) \\ 0.1max. (C{\geq}3.3\muF) \\ [E4] \\ W.V.: 25Vmin.: 0.025max. \\ [F5] \\ W.V.: 25Vmin. \\ : 0.05max. (C{<}0.10\muF) \\ : 0.09max. (C{\geq}0.10\muF) \\ W.V.: 16V/10V: 0.125max. \\ \\ W.V.: 6.3Vmax.: 0.15max. \end{array}$	Solder the capacitor to the test jig (glass epoxy board) in the same manner and under the same conditions as (10). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 55Hz. The frequency range, from 10 to 55Hz and return to 10Hz, should be traversed in approximately 1 minute. This motion should be applied for a period of 2 hours in each of 3 mutually perpendic ular directions (total of 6 hours).			
	12 Deflection		No crack or marked defect should occur.		Solder the capacitor on the test jig (glass epoxy board) shown in Fig. 2 using a eutectic solder. Then apply a force in the direction shown in Fig. 3. The soldering should be done either with an iron or using the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock.			
12			Deflection $ \begin{array}{c} \hline $		20 \$ pressurizing \$ pressurize \$ pressurize 			



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			Specifi						
No.	lte	em	Temperature Compensating Type	High Dielectric Type	Test Method				
13	Solderabi Terminati	llity of on	75% of the terminations are to b continuously.	be soldered evenly and	Immerse the capacitor in a solution of ethanol (JIS rosin (JIS-K-5902) (25% rosin in weight proportion Preheat at 80 to 120°C for 10 to 30 seconds. After immerse in eutectic solder solution for 2±0.5 seco 230±5°C.		ethanol (JIS-K t proportion). onds. After pre 2±0.5 second	-8101) and eheating, s at	
			The measured and observed characteristics should satisfy the specifications in the following table.						
		Appearance	No marking defects						
		Capacitance Change	Within $\pm 2.5\%$ or ± 0.25 pF (Whichever is larger)	R6, R7 : Within ±7.5% E4, F5 : Within ±20%	Preheat the capacitor at 120 to 150°C for 1 minute.		270+5°C		
14	Resistance to Soldering Heat	Q/D.F.	30pFmin. : Q≧1000 30pFmax. : Q≧400+20C C : Nominal Capacitance (pF)	$[R6, R7] \\ W.V.: 25Vmin.: 0.025max. \\ W.V.: 16/10V: 0.035max. \\ W.V.: 6.3V: \\ 0.05max. (C<3.3\muF) \\ 0.1max. (C\geq3.3\muF) \\ [E4] \\ W.V.: 25Vmin.: 0.025max. \\ [F5] \\ W.V.: 25Vmin. \\ : 0.05max. (C<0.10\muF) \\ : 0.09max. (C \geq 0.10\muF) \\ W.V.: 16V/10V: 0.125max. \\ W.V.: 6.3Vmax.: 0.15max. \\ W.V. \\ \end{tabular}$	for 10±0.5 seconds. Let sit at room temperature for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type), then measure. •Initial measurement for high dielectric constant type Perform a heat treatment at 150 ±18°C for one hour and then let sit for 48±4 hours at room temperature. Perform the initial measurement. *Preheating for GRM32/43/55 Step Temperature 1 100°C to 120°C 2 170°C to 200°C				
		I.R.	More than 10,000M Ω or 500 Ω •	F (Whichever is smaller)					
		Dielectric Strength	No failure						
			The measured and observed characteristics should satisfy the specifications in the following table.		_				
		Appearance	No marking defects						
		Capacitance Change	Within $\pm 2.5\%$ or ± 0.25 pF (Whichever is larger)	R6, R7 : Within ±7.5% E4, F5 : Within ±20%	Fix the capacitor to the supporting jig in the same man				inner and
				[R6, R7] W.V. : 25Vmin. : 0.025max. W.V. : 16/10V : 0.035max. W.V. : 6.3V	according to the four heat treatments listed in the following table. Let sit for 24 ± 2 hours (temperature compensating type) or 48 ± 4 hour (high dielectric constant type) at room temperature, then measure.			owing iting type)	
	Tomporaturo			0.05max. (C<3.3µF)	Step	1	2	3	4
15	Cycle	Q/D.F.	30pFmin. : Q≥1000 30pFmax. : Q≥400+20C	0. ππαχ. (C∈3.3μF) [E4] W.V. : 25Vmin. : 0.025max.	Temp. (℃)	Min. Operating Temp.+0/-3	Room Temp.	Max. Operating Temp.+3/-0	Room Temp.
			C. Norminal Capacitance (pr)	[F5]	Time (min.)	30±3	2 to 3	30±3	2 to 3
		W.N W.N W.N	W.V. : 25Vmin. : 0.05max. (C<0.10μF)	•Initial measurement for high dielectric constant type Perform a heat treatment at $150 \pm 18^{\circ}$ for one hour and then let sit for 48 ± 4 hours at room temperature. Perform the initial measurement.			and then		
		I.R.	More than 10,000M Ω or 500 Ω •	F (Whichever is smaller)					
		Dielectric Strength No failure							



Continued from the preceding page.

	Item		Specifications		
No.			Temperature Compensating Type High Dielectric Type		Test Method
			The measured and observed characteristics should satisfy the specifications in the following table.		
16		Appearance	No marking defects	1	
		Capacitance Change	Within ±5% or ±0.5pF (Whichever is larger)	R6, R7 : Within ±12.5% E4, F5 : Within ±30%	
	Humidity Steady State	Q/D.F.	30pF and over : Q \geq 350 10pF and over 30pF and below : Q \geq 275+5C/2 10pF and below : Q \geq 200+10C C : Nominal Capacitance (pF)	<pre>[R6, R7] W.V. : 25Vmin. : 0.05max. W.V. : 16/10V : 0.05max. W.V. : 6.3V 0.075max. (C<3.3µF) 0.125max. (C≥3.3µF) [E4] W.V. : 25Vmin. : 0.05max. [F5] W.V. : 25Vmin. : 0.075max. (C<0.10µF) : 0.125max. (C≥0.10µF) W.V. : 16V/10V : 0.15max. W.V. : 6.3Vmax. : 0.2max.</pre>	Let the capacitor sit at 40±2°C and 90 to 95% humidity for 500±12 hours. Remove and let sit for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type) at room tem- perature, then measure.
		I.R.	More than 1,000M Ω or 50 $\Omega \bullet F$	(Whichever is smaller)	
		Dielectric Strength	No failure		
			The measured and observed ch specifications in the following ta	aracteristics should satisfy the ble.	
		Appearance	No marking defects		
		Capacitance Change	Within ±7.5% or ±0.75pF (Whichever is larger)	R6, R7 : Within ±12.5% E4 : Within ±30% F5 : Within ±30% [W.V. : 10Vmax.] F5 : Within +30/-40%	
17	Humidity Load	Q/D.F.	30pF and over : Q≥200 30pF and below : Q≥100+10C/3 C : Nominal Capacitance (pF)	<pre>[R6, R7] W.V. : 25Vmin. : 0.05max. W.V. : 16/10V : 0.05max. W.V. : 6.3V 0.075max. (C<3.3µF) 0.125max. (C≥3.3µF) [E4] W.V. : 25Vmin. : 0.05max. [F5] W.V. : 25Vmin. : 0.075max. (C<0.10µF) : 0.125max. (C≥0.10µF) W.V. : 16V/10V : 0.15max. W.V. : 6.3Vmax. : 0.2max.</pre>	 Apply the rated voltage at 40±2°C and 90 to 95% humidity for 500±12 hours. Remove and let sit for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type) at room temperature, then measure. The charge/discharge current is less than 50mA. Initial measurement for F5/10V max. Apply the rated DC voltage for 1 hour at 40±2°C. Remove and let sit for 48±4 hours at room temperature. Perform initial measurement.
		I.R.	More than 500M Ω or 25 $\Omega \bullet F$ (V	Vhichever is smaller)	
		Dielectric Strength No failure			



Continued from the preceding page.

	Item		Specifications			
No.			Temperature Compensating Type	High Dielectric Type	Test Method	
			The measured and observed characteristics should satisfy the specifications in the following table.			
		Appearance	No marking defects			
		Capacitance Change	Within ±3% or ±0.3pF (Whichever is larger)	R6, R7 : Within ±12.5% E4 : Within ±30% F5 : Within ±30% (Cap<1.0μF) F5 : Within +30/−40% (Cap≧1.0μF)	Apply 200% of the rated voltage for 1000±12 hours at the	
18	High Temperature Load	Q/D.F.	30pF and over : Q≧350 10pF and over 30pF and below : Q≧275+5C/2 10pF and below : Q≧200+10C C : Nominal Capacitance (pF)	[R6, R7] W.V. : 25Vmin. : 0.05max. W.V. : 16/10V : 0.05max. W.V. : 6.3V 0.075max. (C<3.3µF) 0.125max. (C≥3.3µF) [E4] W.V. : 25Vmin. : 0.05max [F5] W.V. : 25Vmin. : 0.075max. (C<0.10µF) : 0.125max. (C≥0.10µF) W.V. : 16V/10V : 0.15max. W.V. : 6.3Vmax. : 0.2max.	maximum operating temperature ±3°C. Let sit for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type) at room temperature, then measure. The charge/discharge current is less than 50mA. •Initial measurement for high dielectric constant type. Apply 200% of the rated DC voltage for one hour at the maximum operating temperature ±3°C. Remove and let sit for 48±4 hours at room temperature. Perform initial measurement. *150% for 500V and C≥10µF	
		I.R.	More than 1,000M Ω or 50 Ω •F (, Whichever is smaller)		
		Dielectric Strength	No failure			

Table A

	Nominal Values (ppm/°c)*	Capacitance Change from 25°C (%)					
Char. Code		-55		-30		-10	
		Max.	Min.	Max.	Min.	Max.	Min.
5C	0 ± 30	0.58	-0.24	0.40	-0.17	0.25	-0.11
6C	0 ± 60	0.87	-0.48	0.59	-0.33	0.38	-0.21
6P	-150 ± 60	2.33	0.72	1.61	0.50	1.02	0.32
6R	-220 ± 60	3.02	1.28	2.08	0.88	1.32	0.56
6S	-330 ± 60	4.09	2.16	2.81	1.49	1.79	0.95
6T	-470 ± 60	5.46	3.28	3.75	2.26	2.39	1.44
7U	-750 ±120	8.78	5.04	6.04	3.47	3.84	2.21
1X	+350 to -1000	-	_	-	-	-	-

*Nominal values denote the temperature coefficient within a range of 25℃ to 125℃ (for △C)/85℃ (for other TC).

